

# Universal quantum logic in hot silicon qubits

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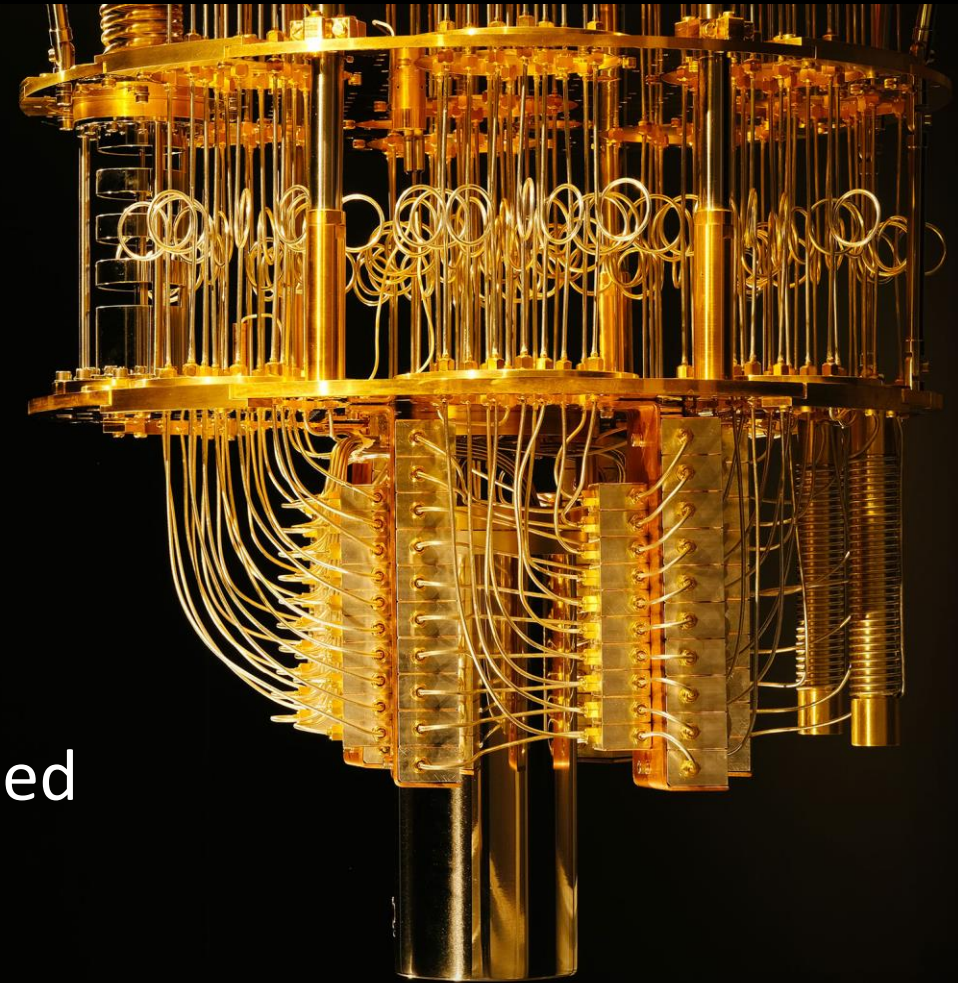
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Simon Geyer, group meeting talk 13 Dec 2019

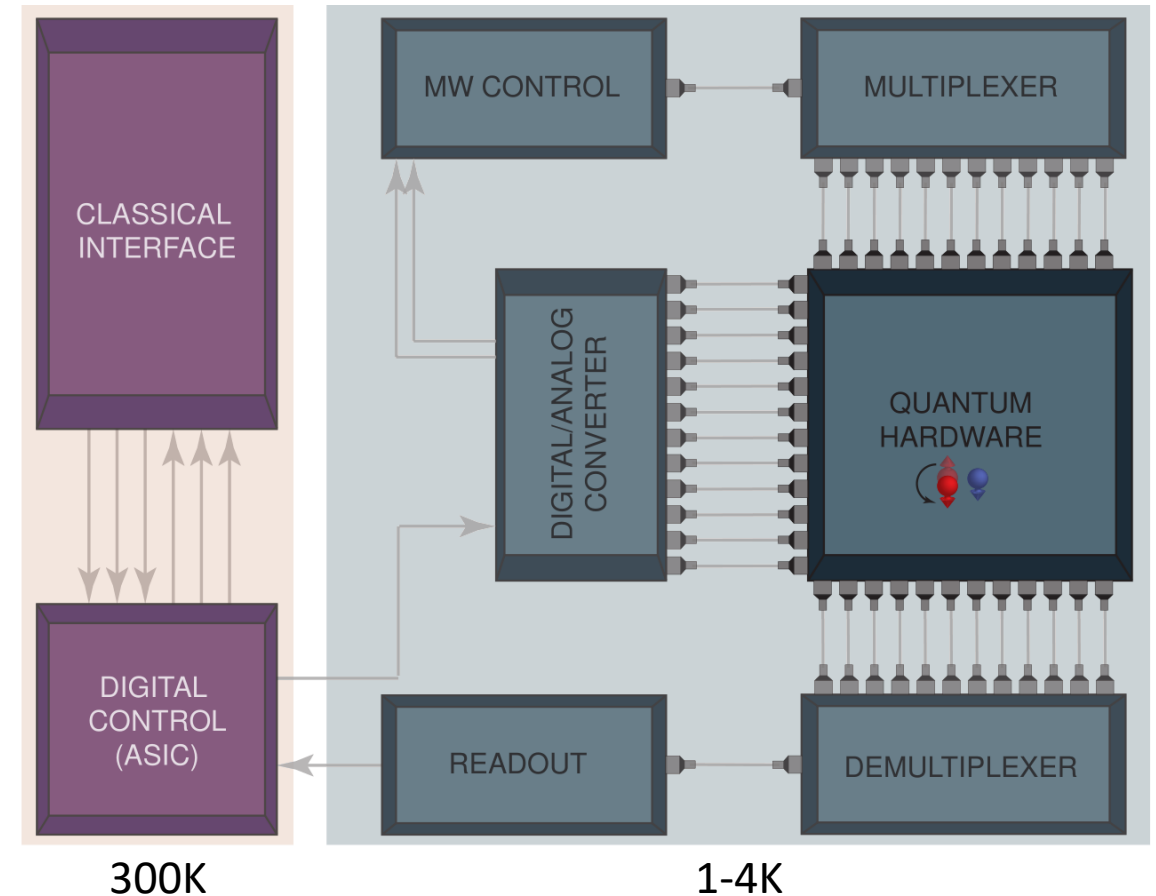
# Large-scale quantum computing

- scalable qubit
- scalable architecture
- problems:
  - bottleneck of interconnections to RT electronics
  - many qubits -> high cooling power needed



# Idea: quantum integrated circuit


- quantum integrated circuit
  - on-chip electronics for qubit-control
  - no interconnection bottleneck
  - dissipates large amount of heat -> more cooling needed



# Idea: quantum integrated circuit

- Why should we operate at 1-4K?
  - on-chip electronic and large number of qubits generate heat
  - cooling power increases with temperature

technology	temperture (K)	typical cooling power (W)
$^4\text{He}$	4.2	
1K pot	1.8	$10^{-1}$
$^3\text{He}$	0.8	$10^{-2}$
$^3\text{He}/^4\text{He}$ -dilution refrigerator	$20 \times 10^{-3}$	$10^{-5}$



cooling power increases by factor  $10^4$

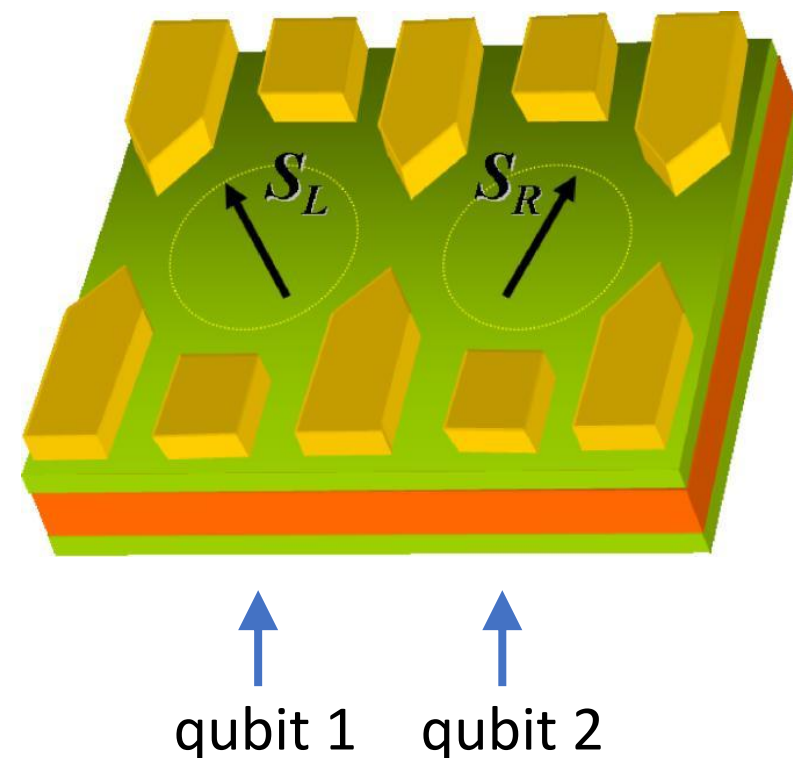
- challenge: good qubit properties at high T

# Loss-DiVincenzo spin qubit

- confine electrons in QDs
- encode information in spin of a single electron<sup>1</sup>
- qubit states  $|0\rangle$  and  $|1\rangle$ :

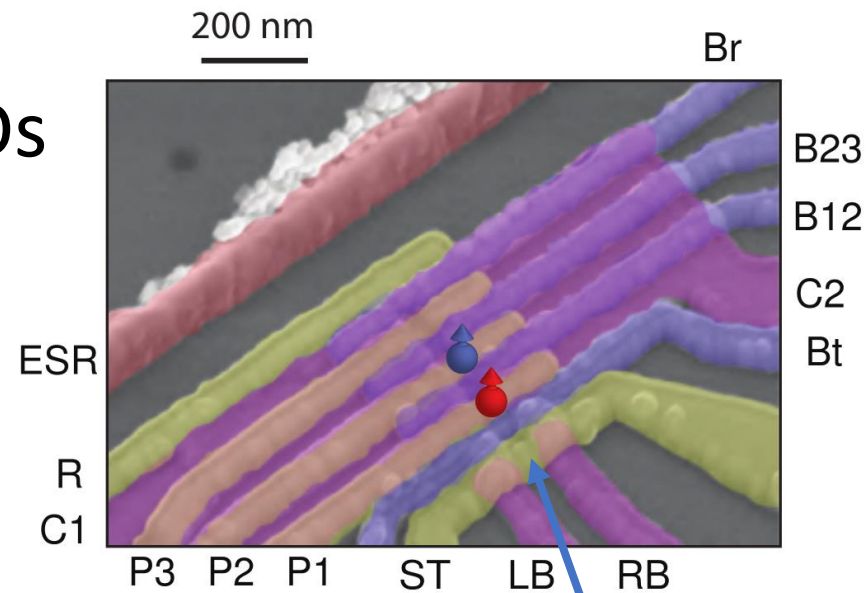
$$|0\rangle = |\uparrow\rangle$$

$$|1\rangle = |\downarrow\rangle$$

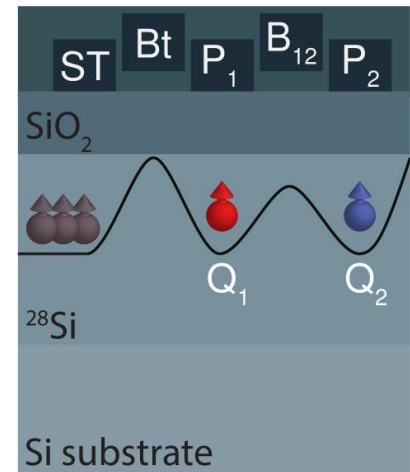


# Device

- $^{28}\text{Si}$  substrate (spins-free)
- P-gates accumulate  $e^-$ -QDs at Si-SiO<sub>2</sub> interface
- B-gates tune tunnel barriers
- charge sensor
- MW antenna for ESR

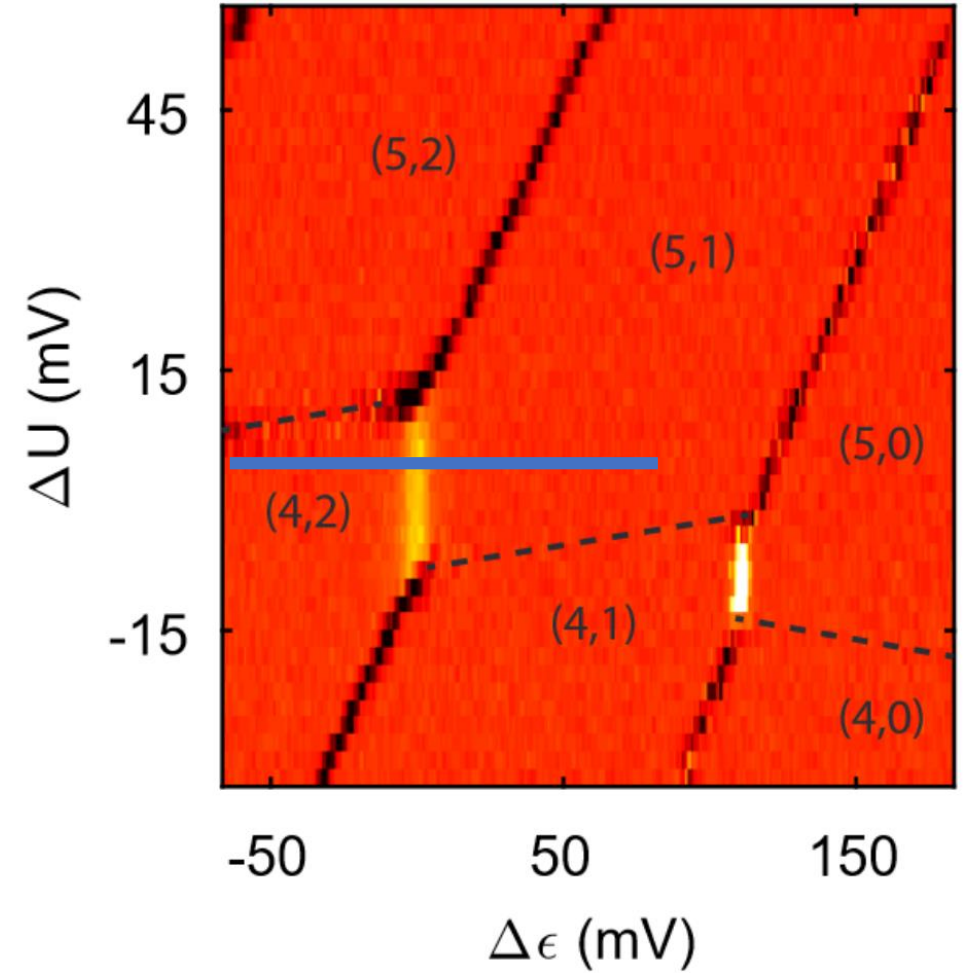
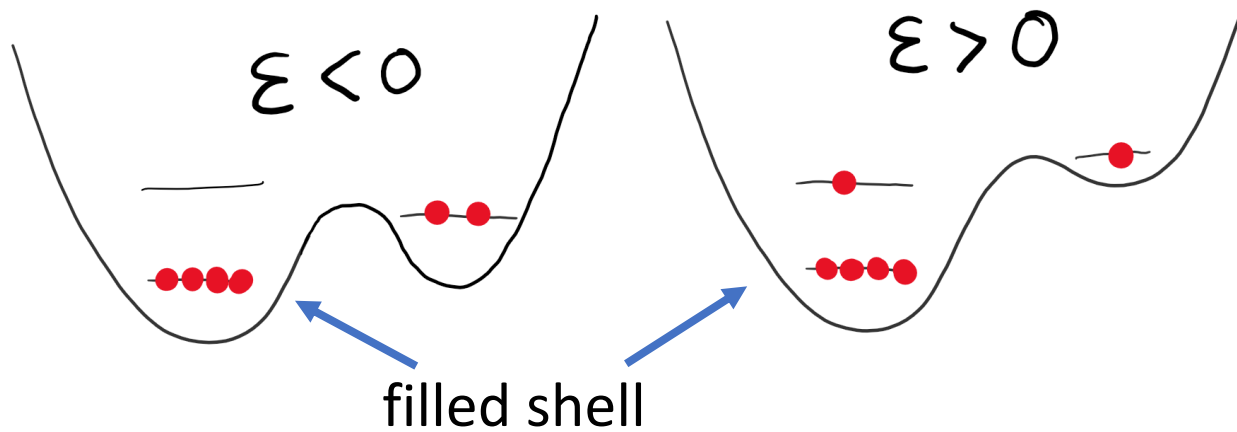


charge sensing SET

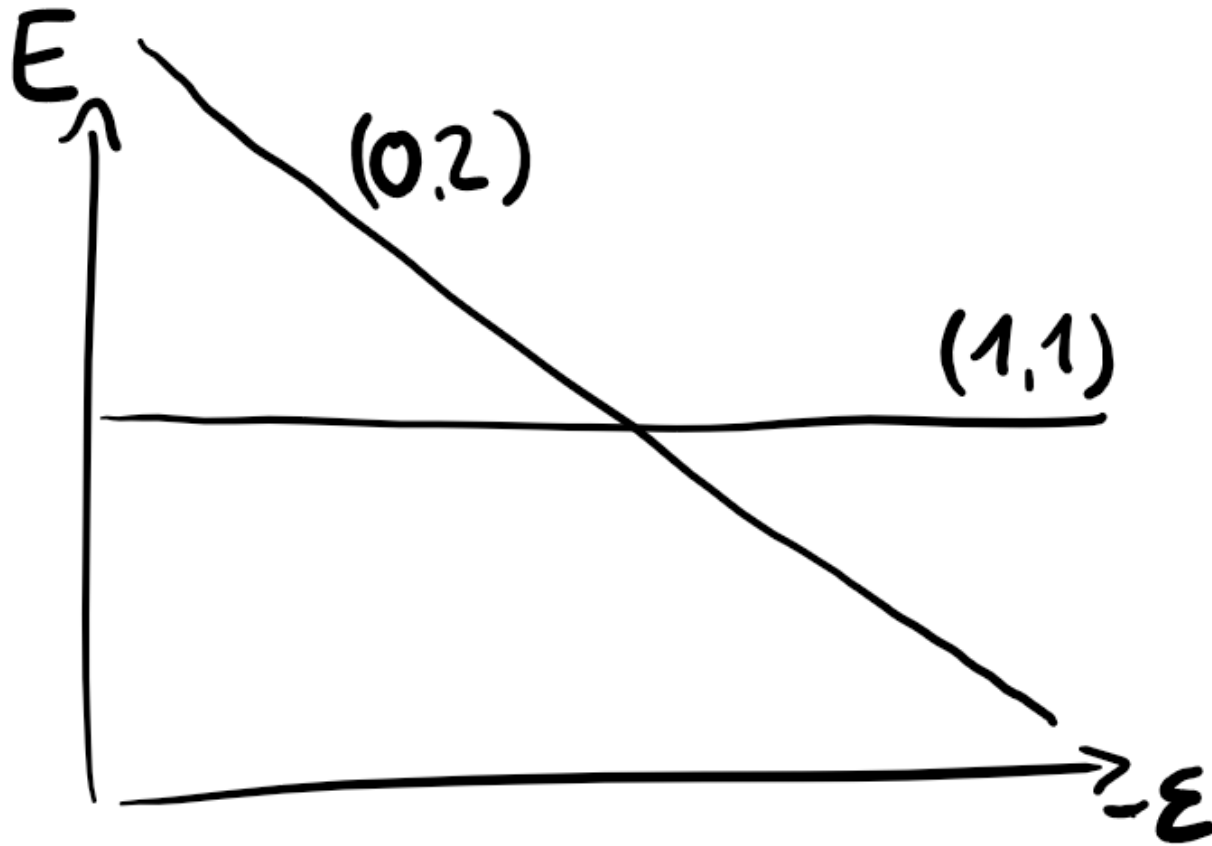


# Double QD

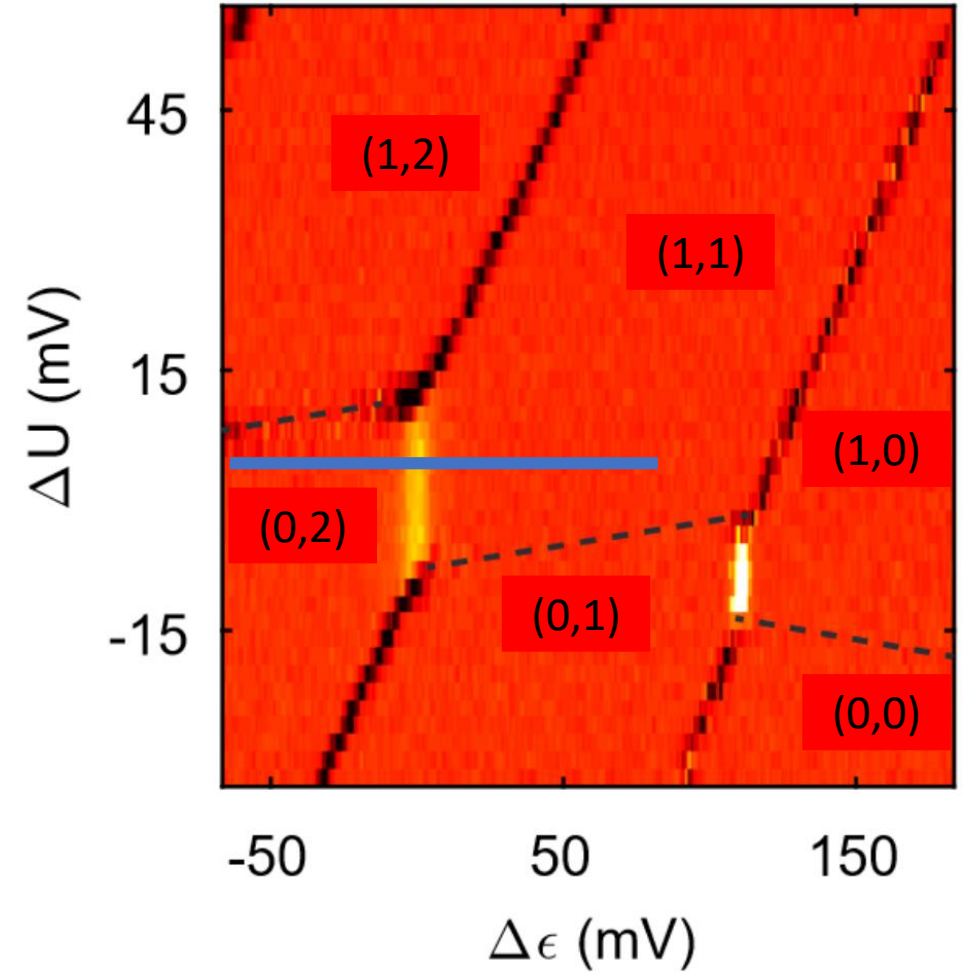
- 4 electrons in left dot fill shell  
-> only use valence electrons



# Double QD – states

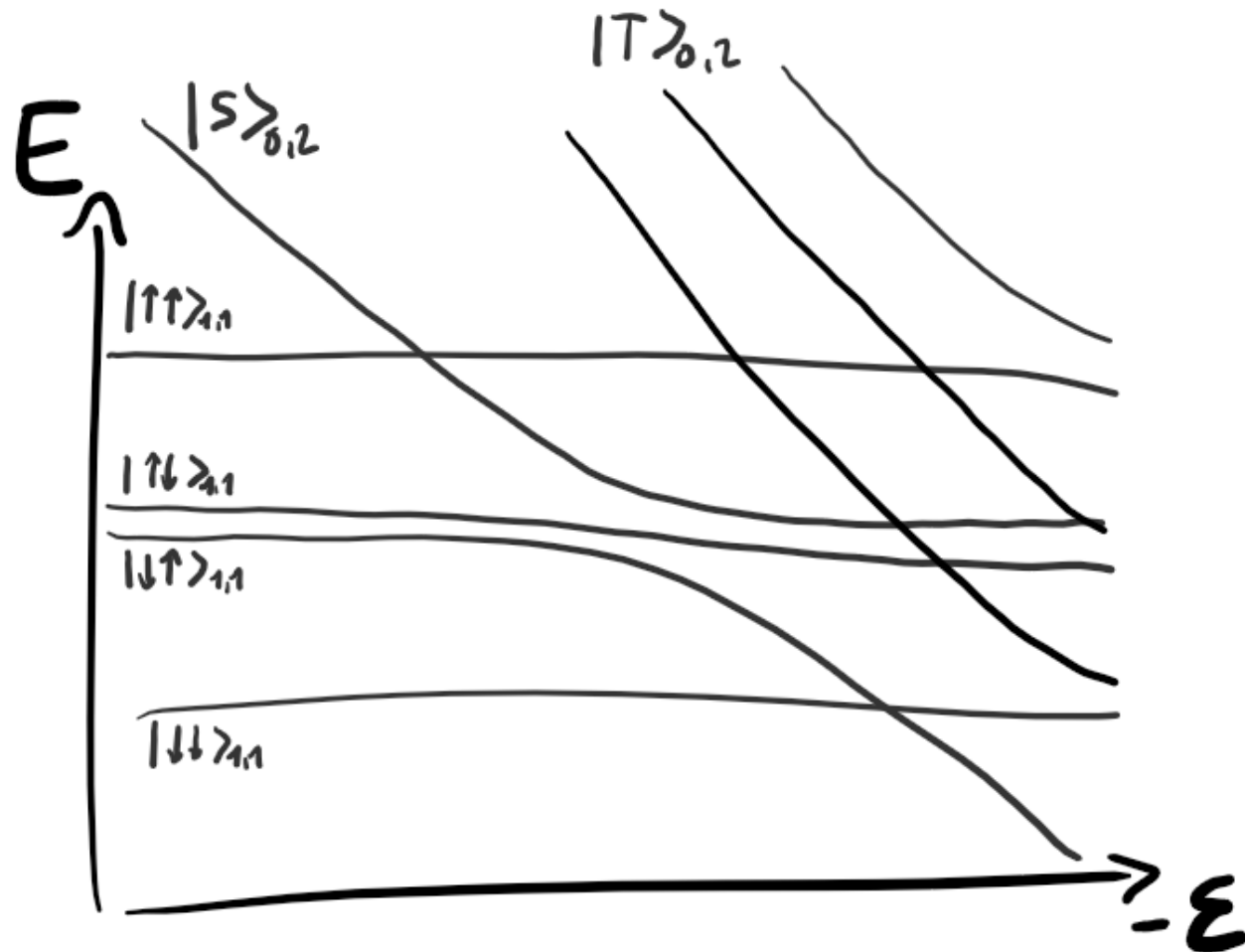


equivalent:

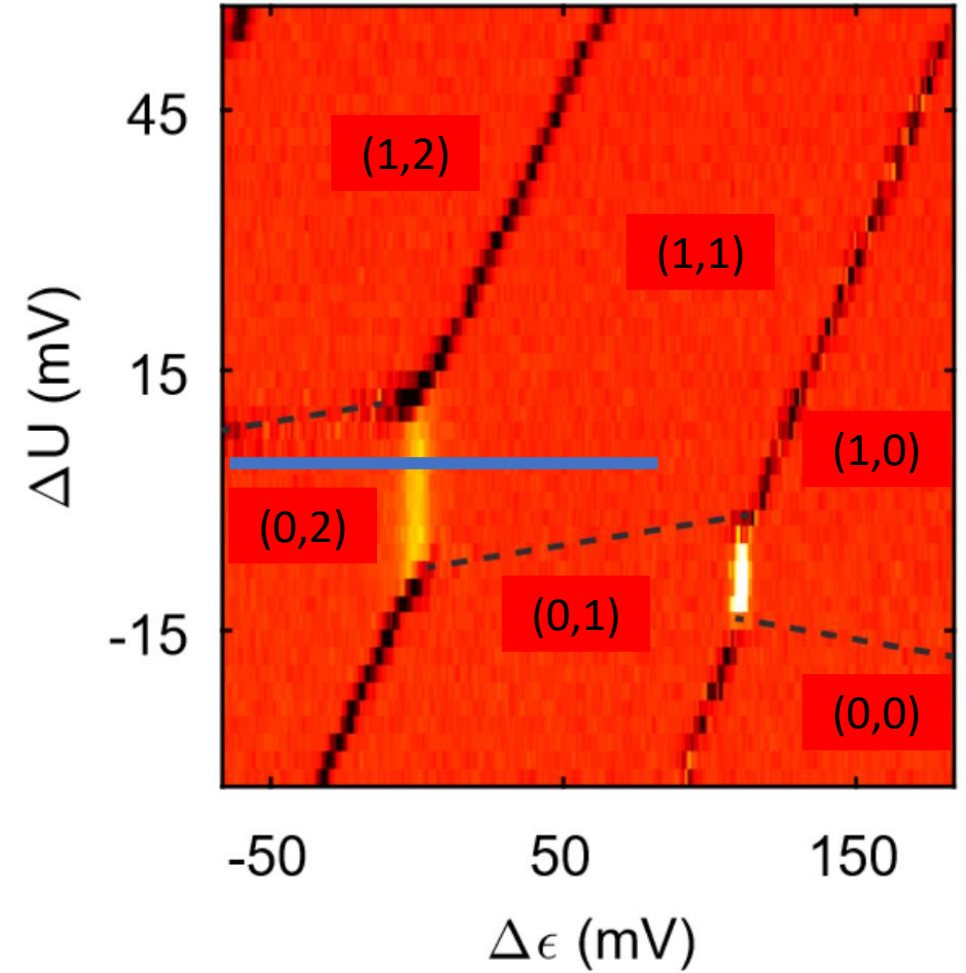




# Double QD – states

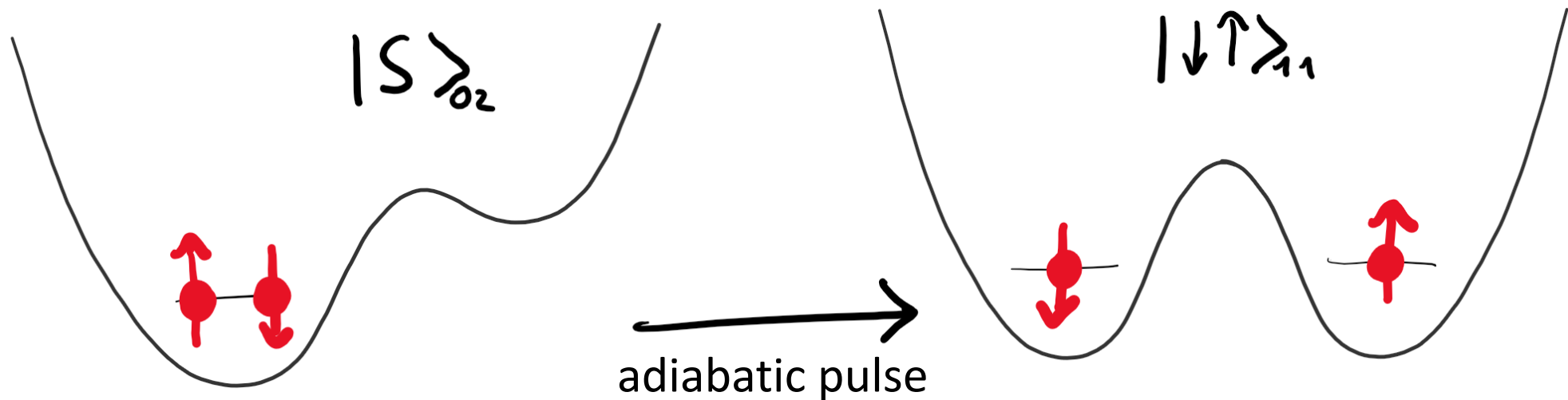
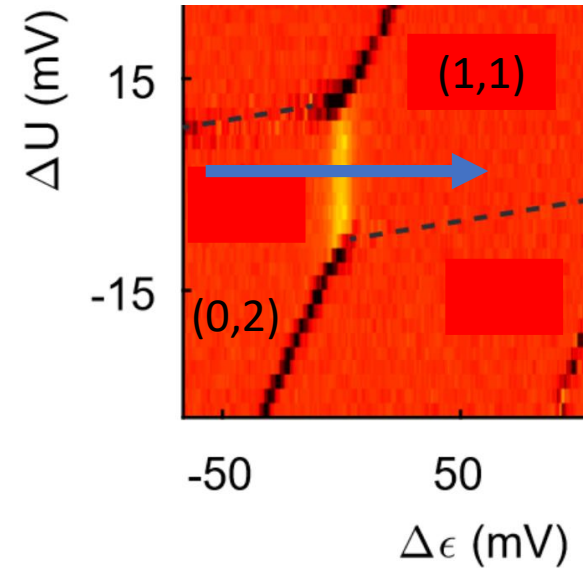


equivalent:



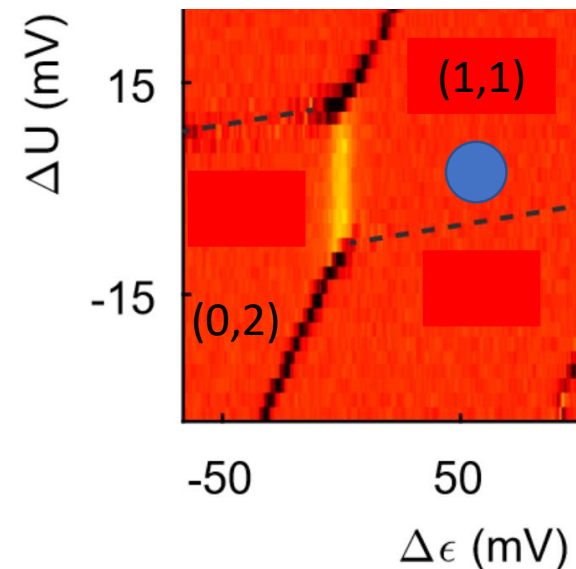
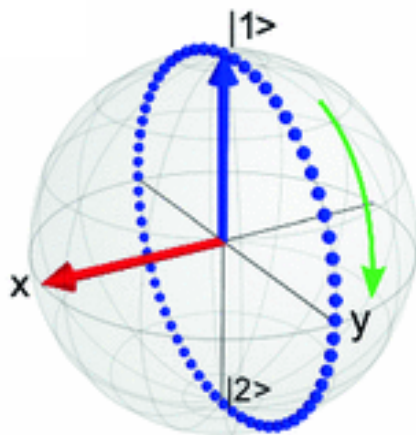
# Initializing the qubit

- goal: well-defined state, e.g.  $|du\rangle_{11}$
- use fast spin relaxation in (0,2) charge state to populate  $|S\rangle_{02}$  ground state
- adiabatic pulse to (1,1) gives  $|du\rangle_{11}$

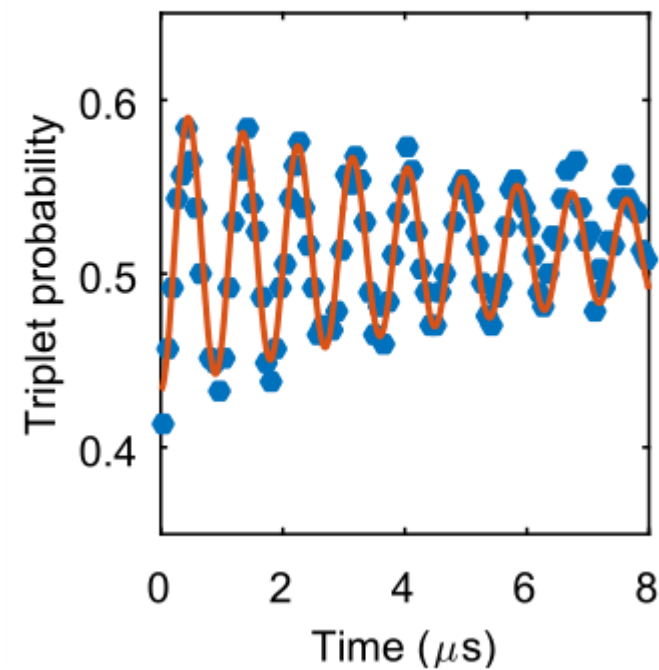


# Manipulation

- MW signal  $\rightarrow$  oscillating B-field rotates spin  $\rightarrow$  arbitrary single-qubit rotations
- slightly different resonance frequency  $\rightarrow$  allows to address qubits individually

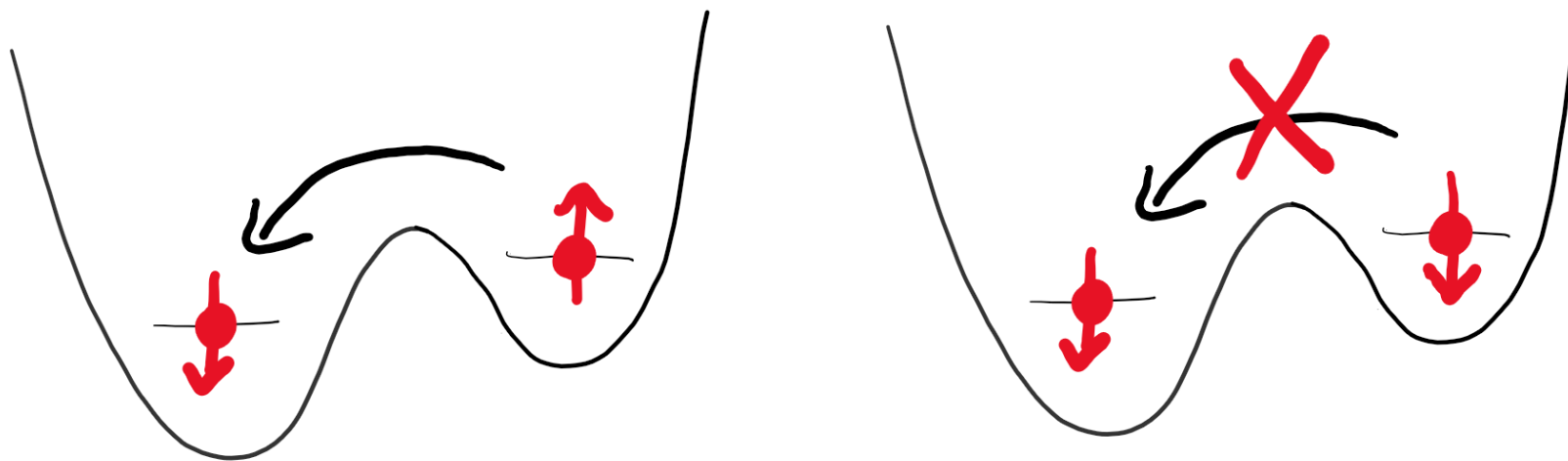
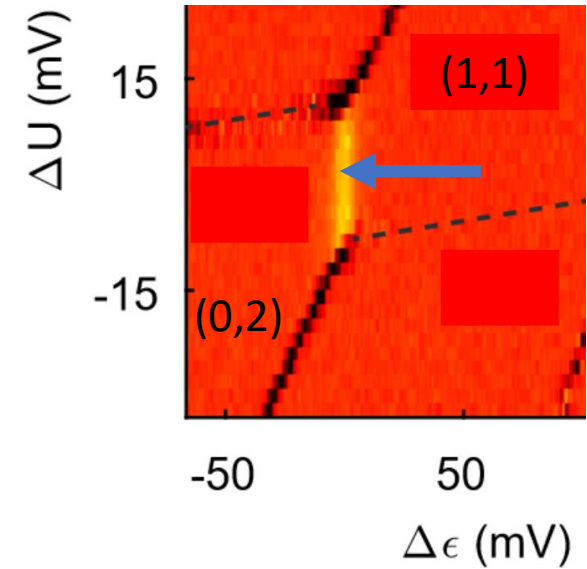


$T = 1.1$  K

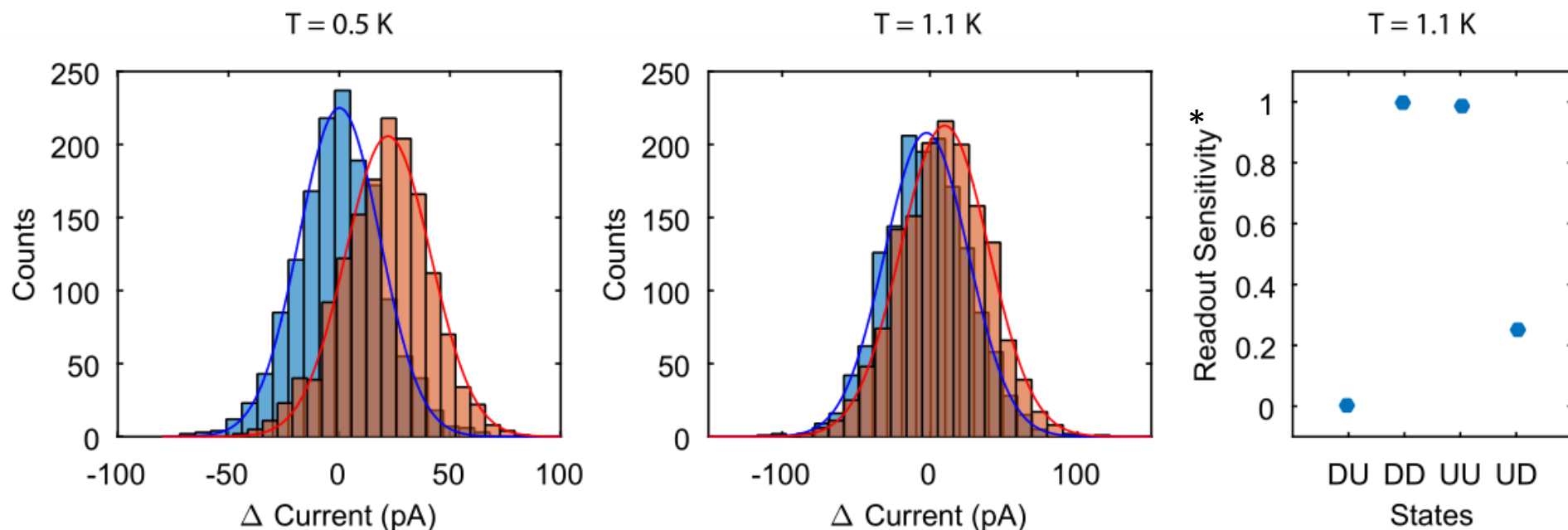


# Readout

- spin-to-charge conversion:
  - singlet  $\rightarrow$  current
  - triplet  $\rightarrow$  no current
- only one qubit can be read out



# Readout

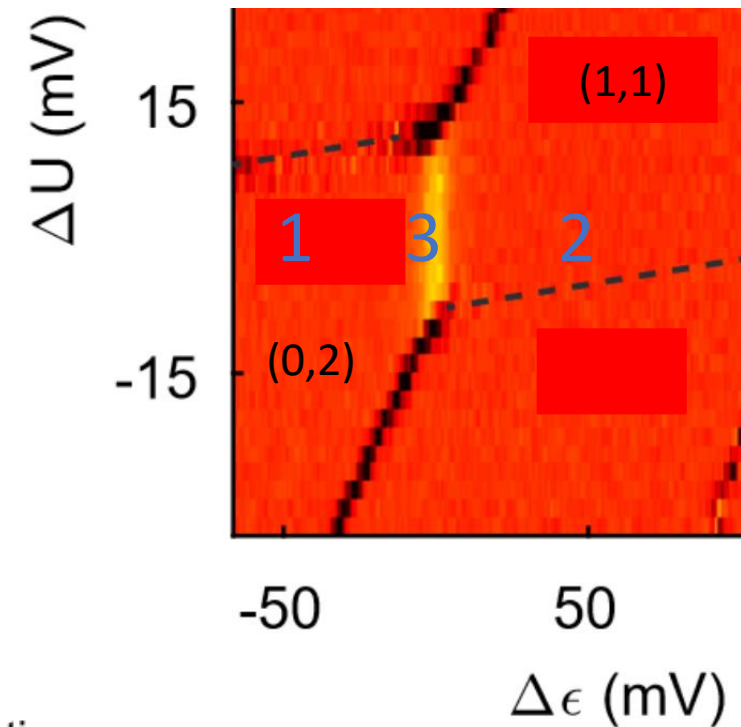
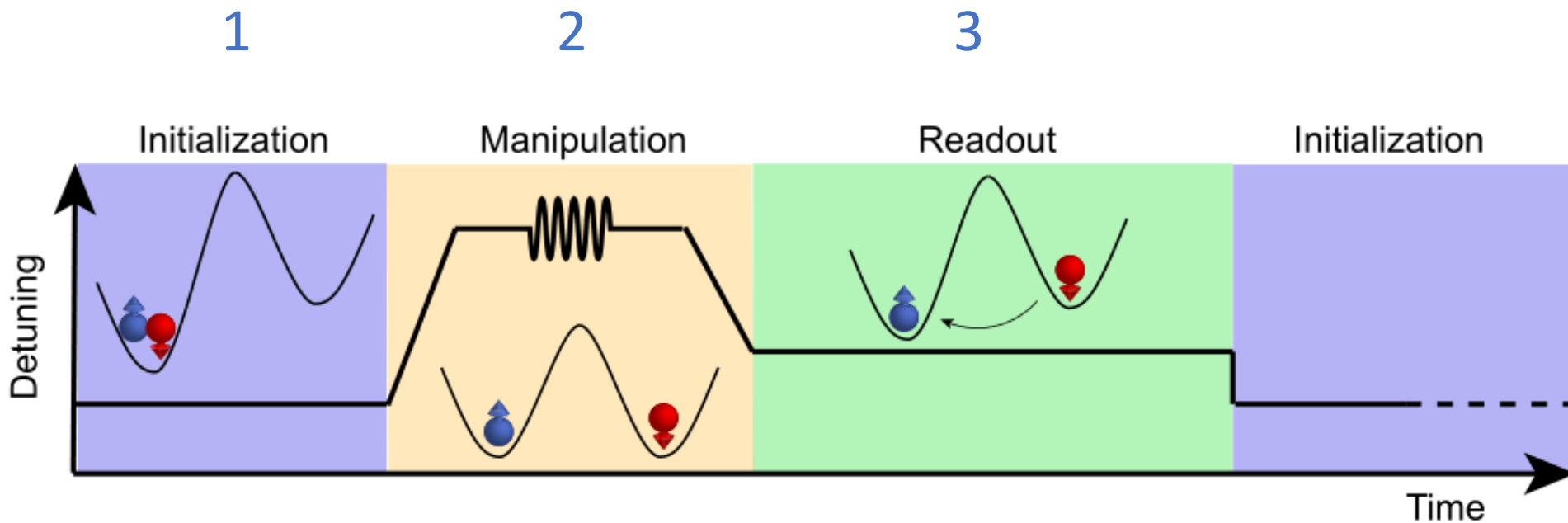


- different current measured for singlet and triplet states
- $|ud\rangle_{11}$  mixes with singlet  $\rightarrow$  hard to distinguish
- alternative: parity-readout<sup>1</sup>

<sup>1</sup>Yang et al., arXiv: 1902.09126 (2019)

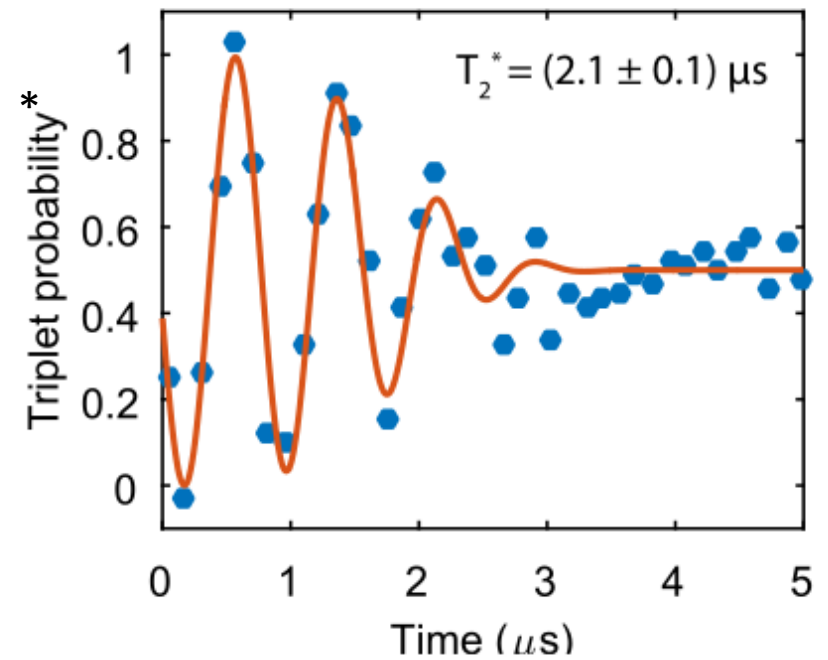
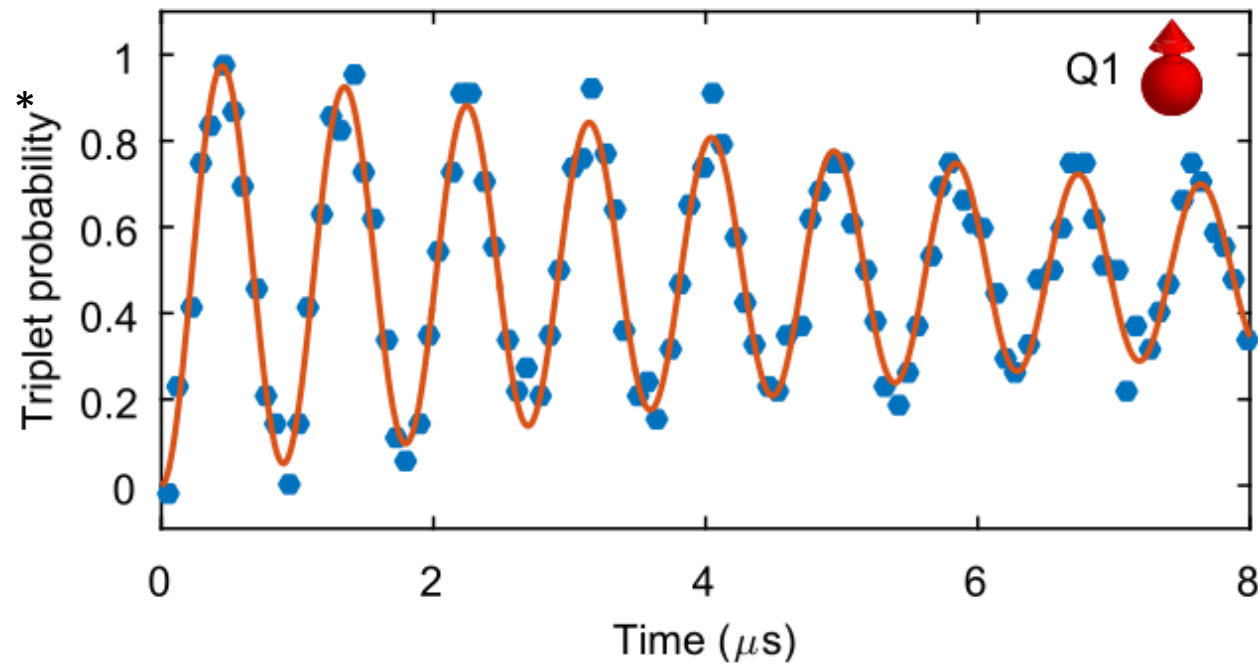
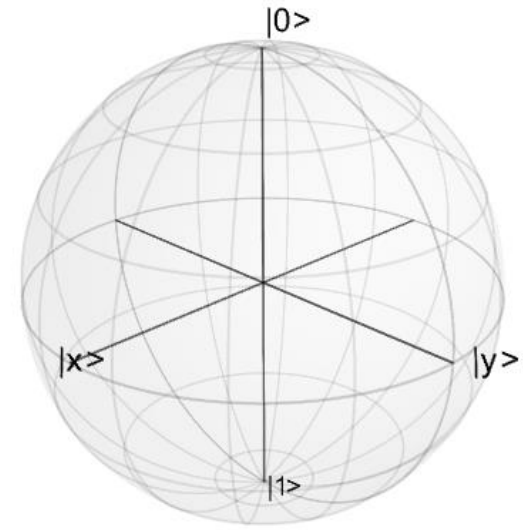
\*normalized

# Qubit operation cycle



# Single-qubit characterization

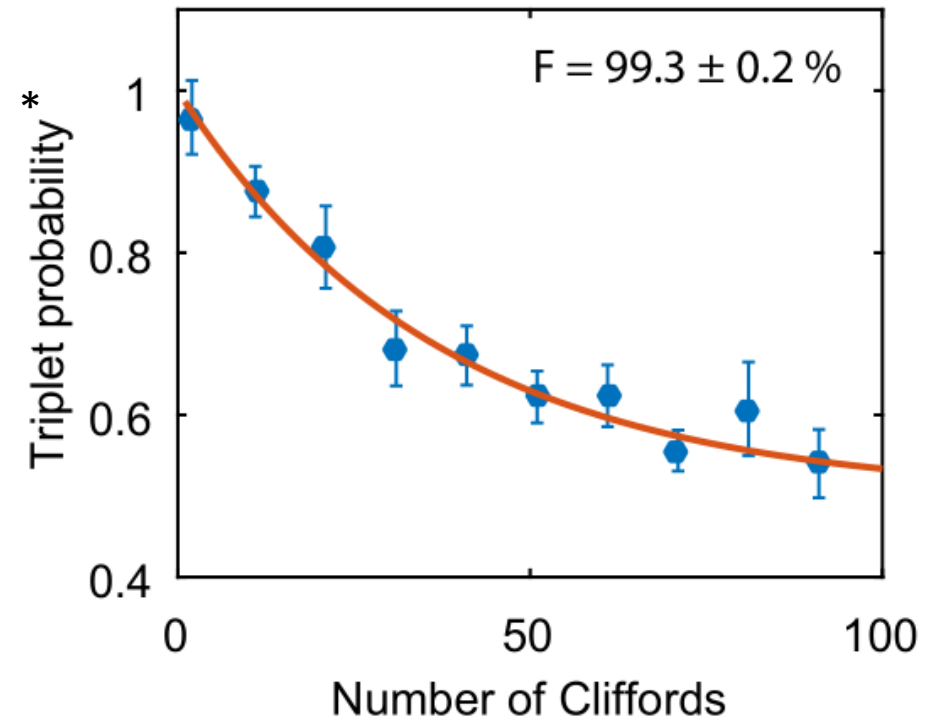
- Rabi oscillations: constant drive
- Ramsey sequence: dephasing at equator



\*normalized

# Single-qubit gate fidelity

- randomized benchmarking:
  - apply certain number of random Clifford gates
  - go to triplet state
  - read out
- fit yields fidelities  $\sim 99\%$  for one single-qubit gate
- readout errors have no influence on this method

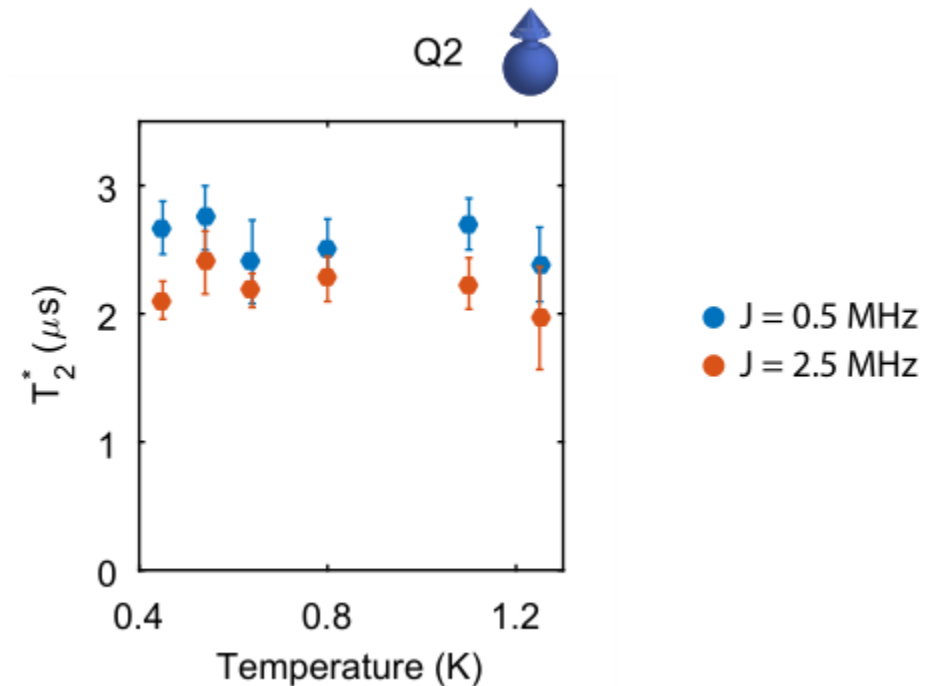
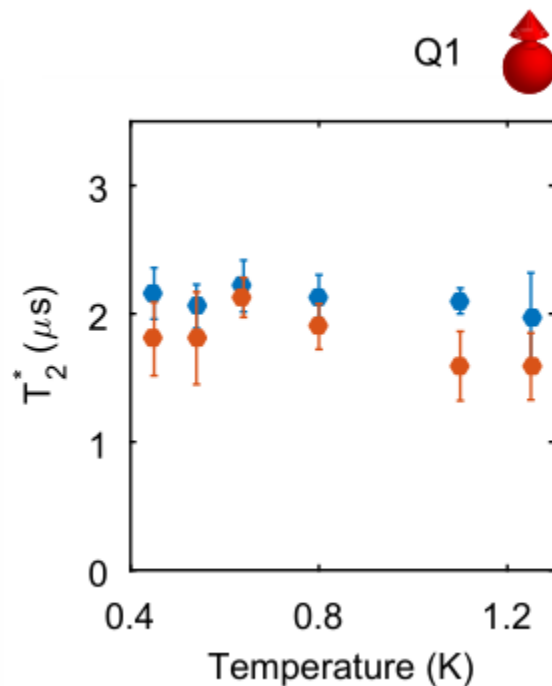


\*normalized



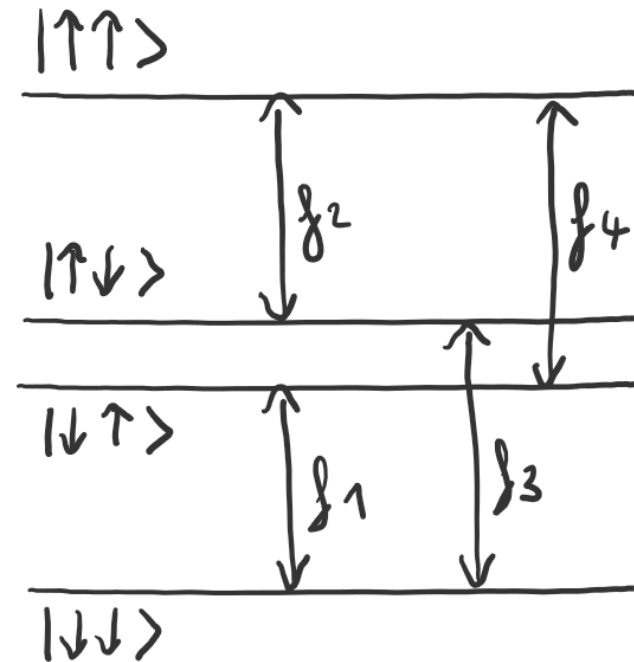
# Hot spin qubits

- so far:  $T = 1.1\text{K}$
- $T_2^*$  only weakly dependent on  $T$
- limiting factor<sup>1</sup>:  
 $T_1 \propto T^{-5}$

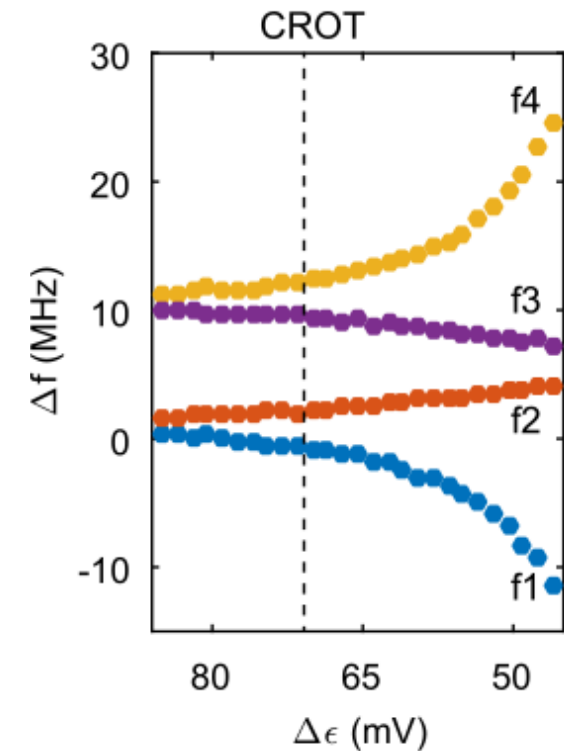


# Two-qubit characterization

- exchange interaction couples spins
- qubit 1 changes resonance frequency depending on state of qubit 2 and vice versa

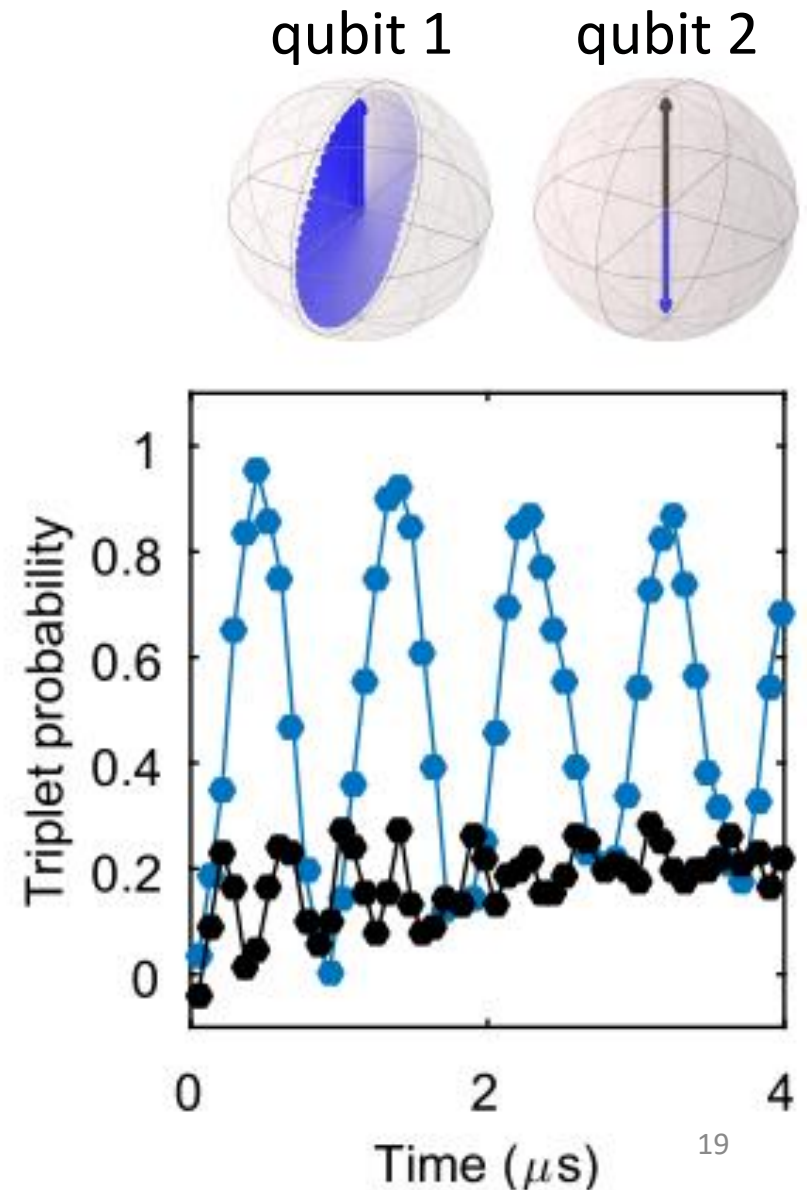


$$H = J \vec{S}_1 \cdot \vec{S}_2 + \sum_i \mu_B g_i \vec{B}_i \cdot \vec{S}_i$$

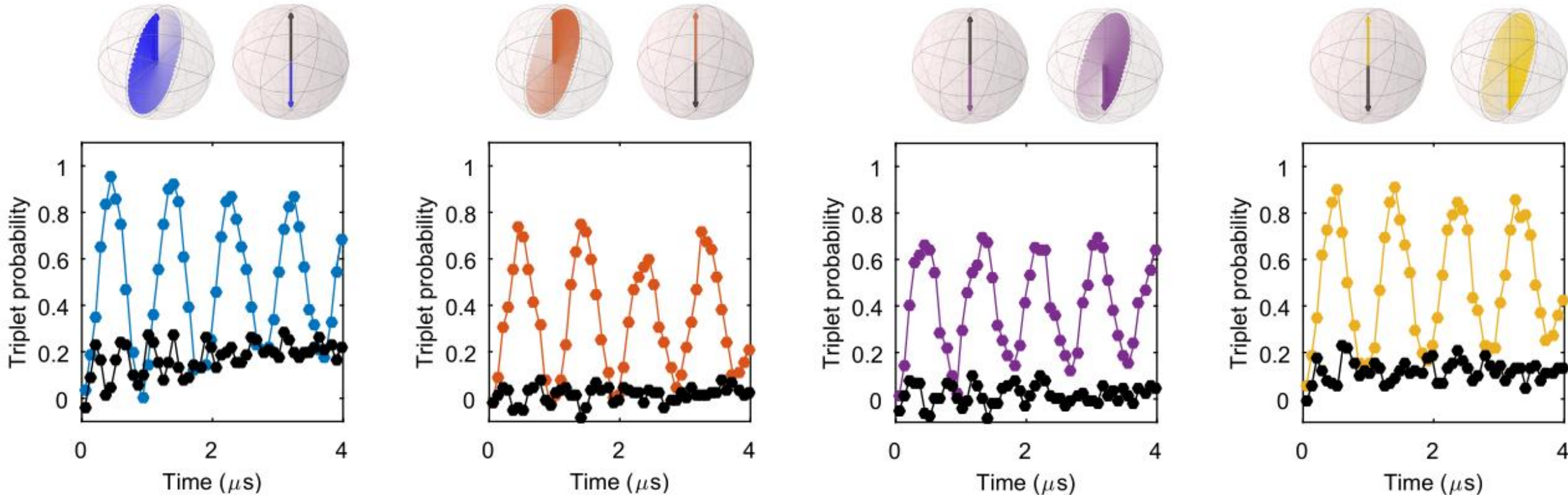


# Two-qubit characterization

- CROT gate (conditional rotation)
- qubit 1 is driven only if qubit 2 is in a certain state
- CROT + single-qubit gates = CNOT
- coherent manipulation
- scalable?



# Two-qubit characterization

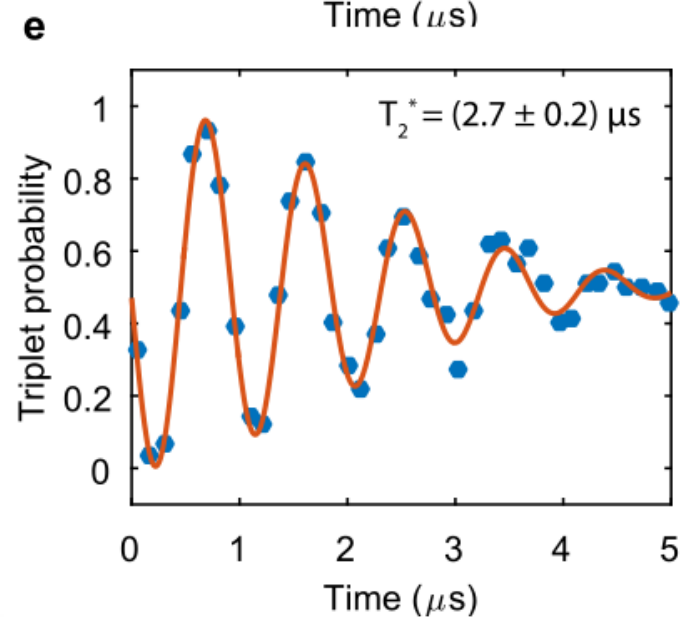
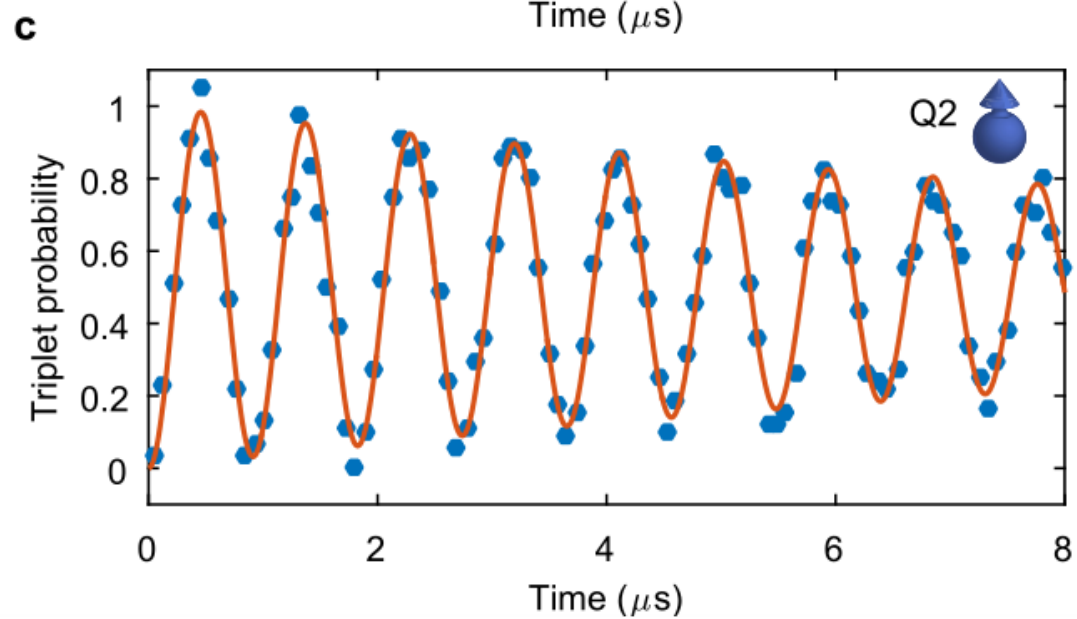
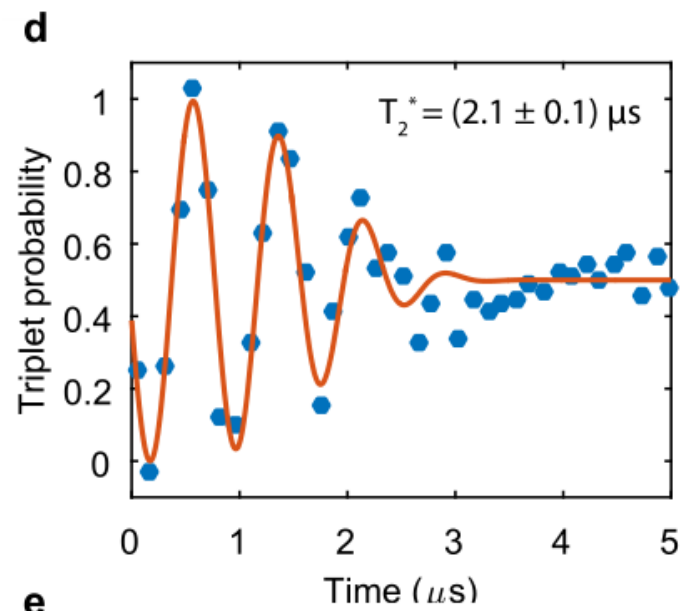
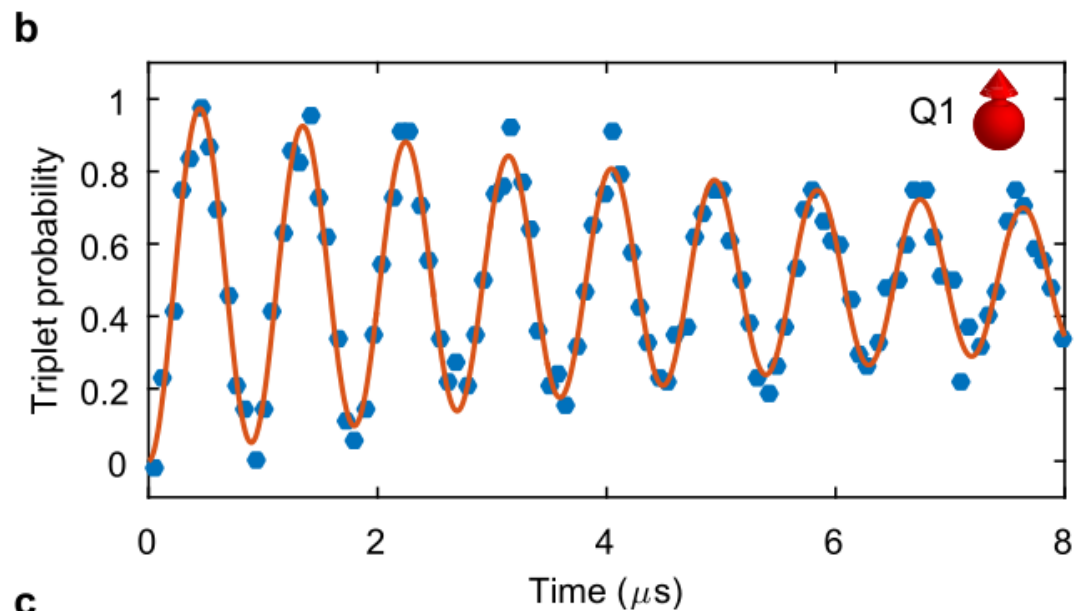


- CROT is realized at all 4 transitions

# Conclusion

- single-qubit gates at 1.1K with high fidelity (99%)
- CROT gate for universal quantum computing at 1.1K
- $T_2^*$  independent of temperature
- 2 qubit readout? readout fidelity at high T?
- scalability of qubit-interactions?

# Appendix



**d**